

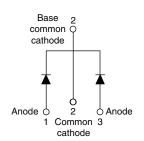
VS-16CTQ...PbF Series, VS-16CTQ...-N3 Series

Vishay Semiconductors

Schottky Rectifier, 2 x 8 A



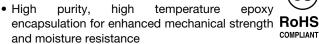
TO-220AB



| PRODUCT SUMMARY | | | | | |
|----------------------------------|-------------------|--|--|--|--|
| Package | TO-220AB | | | | |
| I _{F(AV)} | 2 x 8 A | | | | |
| V_R | 60 V, 80 V, 100 V | | | | |
| V _F at I _F | 0.58 V | | | | |
| I _{RM} max. | 7 mA at 125 °C | | | | |
| T _J max. | 175 °C | | | | |
| Diode variation | Common cathode | | | | |
| E _{AS} | 7.5 mJ | | | | |

FEATURES

- 175 °C T_J operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

This center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | |
|-------------------------------------|---|-------------|----|--|--|--|
| SYMBOL CHARACTERISTICS VALUES UNITS | | | | | | |
| I _{F(AV)} | Rectangular waveform | 16 | Α | | | |
| V _{RRM} | | 60 to 100 | V | | | |
| I _{FSM} | t _p = 5 μs sine | 850 | Α | | | |
| V _F | 8 A _{pk} , T _J = 125 °C (per leg) | 0.58 | V | | | |
| T _J | Range | - 55 to 175 | °C | | | |

| VOLTAGE RATINGS | | | | | | | | | |
|--|------------------|--------------------|--------------------|--------------------|--------------------|--------------------|--------------------|-------|--|
| PARAMETER | SYMBOL | VS- 16CTQ060PbF | VS- 16CTQ060-N3 | VS- 16CTQ080PbF | VS- 16CTQ080-N3 | VS- 16CTQ100PbF | VS- 16CTQ100-N3 | UNITS | |
| Maximum DC reverse voltage | V _R | | | | | | | | |
| Maximum working peak reverse voltage | V _{RWM} | 60 | 60 | 80 | 80 | 100 | 100 | V | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|---------------------------------------|------------|--------------------|--|---|--|-------|---|---|
| PARAMETER | | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | | |
| Maximum average forward current | per leg | - | 50 0/ ditti anala at T = 140 00 materialismos famo | | 50 % duty cycle at T _C = 148 °C, rectangular waveform | | 8 | Α |
| See fig. 5 | per device | I _{F(AV)} | 50 % duty cycle at 1 _C = 146 °C | o, rectangular wavelorm | 16 | | | |
| Maximum peak one cycle non-repetitive | | I | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with rated | 850 | Α | | |
| surge current per leg See fig. 7 | | I _{FSM} | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 275 | A | | |
| Non-repetitive avalanche ener | gy per leg | E _{AS} | $T_J = 25$ °C, $I_{AS} = 0.50$ A, $L = 60$ |) mH | 7.50 | mJ | | |



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| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|--------------------------------------|-----------------|---|------|---|--|--|
| Repetitive avalanche current per leg | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | 0.50 | Α | | |

| ELECTRICAL SPECIFICATIONS | | | | | | |
|--|--------------------------------|---|---------------------------------------|--------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | | VALUES | UNITS | |
| Maximum forward voltage drop per leg See fig. 1 | | 8 A | T _{.1} = 25 °C | 0.72 | V | |
| | V _{FM} ⁽¹⁾ | 16 A | 1j=25 C | 0.88 | | |
| | V _{FM} ('') | 8 A | T 105 °C | 0.58 | | |
| | | 16 A | T _J = 125 °C | 0.69 | | |
| Maximum reverse leakage current per leg | I _{RM} ⁽¹⁾ | T _J = 25 °C | M waterd M | 0.55 | mA | |
| See fig. 2 | IRM ('') | T _J = 125 °C | V _R = rated V _R | 7.0 | | |
| Threshold voltage | V _{F(TO)} | T T maximum | | 0.415 | V | |
| Forward slope resistance | r _t | $T_J = T_J$ maximum | | 11.07 | mΩ | |
| Maximum junction capacitance per leg | Ст | $V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C | | 500 | pF | |
| Typical series inductance per leg | L _S | Measured lead to lead 5 m | 8.0 | nH | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs | |

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

| THERMAL - MECHANICAL SF | THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | |
|---|-------------------------------------|--------------------------------------|-------------|------------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | - 55 to 175 | °C | | | | |
| Maximum thermal resistance, junction to case per leg | R _{thJC} | DC operation | 3.25 | °C/W | | | | |
| Maximum thermal resistance junction to case per package | R _{thJC} | DC operation | 1.63 | O, W | | | | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased | 0.50 | | | | | |
| Approximate weight | | | 2 | g | | | | |
| Approximate weight | | | 0.07 | OZ. | | | | |
| Mounting torque minimum | | | 6 (5) | kgf · cm | | | | |
| Mounting torque — maximum | | | 12 (10) | (lbf · in) | | | | |
| | | | 16CT | Q060 | | | | |
| Marking device | | Case style TO-220AB | 16CTQ080 | | | | | |
| | | | 16CTQ100 | | | | | |

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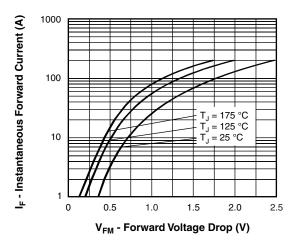


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

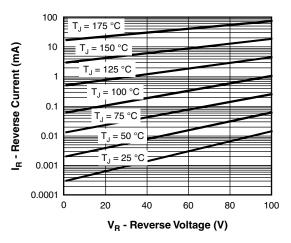


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

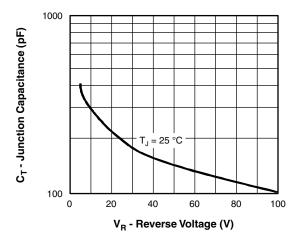


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

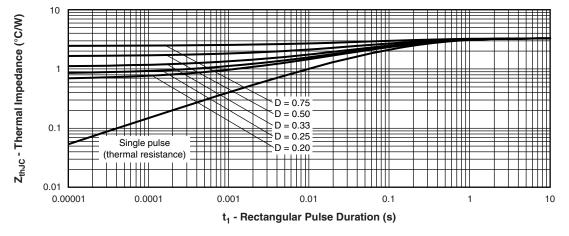


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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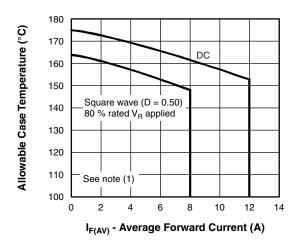


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

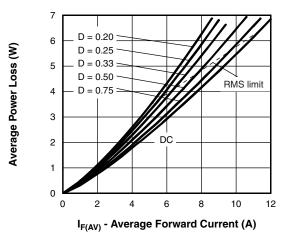


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

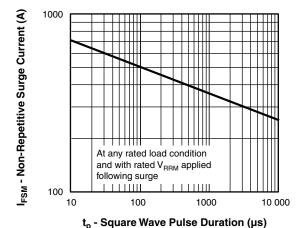


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

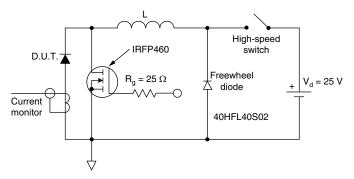


Fig. 8 - Unclamped Inductive Test Circuit

Note

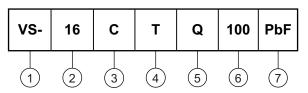
 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R applied

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (16 = 16 A)

Circuit configuration

C = Common cathode

4 - Package

T = TO-220

5 - Schottky "Q" series

060 = 60 V 080 = 80 V

6 - Voltage rating

100 = 100 V

7 - Environmental digit

- PbF = Lead (Pb)-free and RoHS compliant
- -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | |
| VS-16CTQ060PbF | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-16CTQ060-N3 | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-16CTQ080PbF | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-16CTQ080-N3 | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-16CTQ100PbF | 50 | 1000 | Antistatic plastic tube | | | | |
| VS-16CTQ100-N3 | 50 | 1000 | Antistatic plastic tube | | | | |

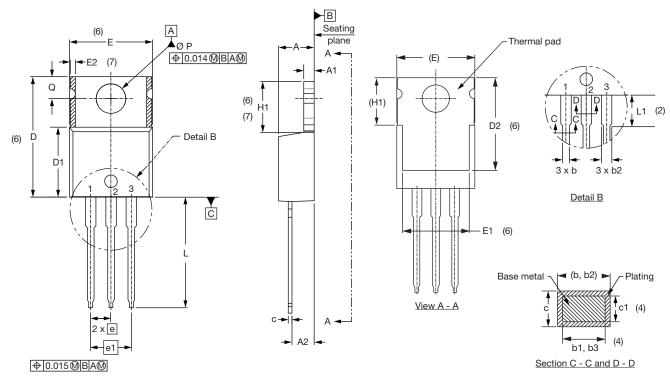
| LINKS TO RELATED DOCUMENTS | | | | |
|--|--------------|--------------------------|--|--|
| Dimensions <u>www.vishay.com/doc?95222</u> | | | | |
| Post and the lafe matter | TO-220AB PbF | www.vishay.com/doc?95225 | | |
| Part marking information | TO-220AB -N3 | www.vishay.com/doc?95028 | | |
| SPICE model | | www.vishay.com/doc?95279 | | |



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead tip

Lead assignments

<u>Diodes</u>

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

| SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|--------|--------|--------|-------|-------|-------|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.25 | 4.65 | 0.167 | 0.183 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 |

| SYMBOL | MILLIM | IETERS | INCHES | | NOTES |
|---------|------------|--------|--------|-------|-------|
| STIMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| Е | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 |
| E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| E2 | - | 0.76 | - | 0.030 | 7 |
| е | 2.41 | 2.67 | 0.095 | 0.105 | |
| e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6, 7 |
| L | 13.52 | 14.02 | 0.532 | 0.552 | |
| L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| ØΡ | 3.54 | 3.73 | 0.139 | 0.147 | |
| Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| θ | 90° to 93° | | 90° t | o 93° | |
| | | | | | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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